

TECHNICAL DATA DATA SHEET 454, REV. -

# HERMETIC POWER SCHOTTKY RECTIFIER Ultra Low Reverse Leakage Very Low Voltage Drop

DESCRIPTION: A 100 VOLT, 30 AMP, POWER SCHOTTKY RECTIFIER IN A HERMETIC TO-254 PACKAGE.

MAXIMUM RATINGS

ALL RATINGS ARE @  $T_C = 25 \ ^{\circ}C$  UNLESS OTHERWISE SPECIFIED.

RATING	SYMBOL	MAX.	UNITS
PEAK INVERSE VOLTAGE	PIV	100	Volts
MAXIMUM DC OUTPUT CURRENT (With Cathode Maintained @ $T_c=100$ °C) (SINGLE) Total Current Limited by Die.	l <sub>o</sub>	30	Amps
MAXIMUM DC OUTPUT CURRENT (With Cathode Maintained @ $T_c=100$ °C) (COMMON CATHODE). Current Limited by Device.	lo	35	Amps
MAXIMUM NONREPETITIVE FORWARD SURGE CURRENT (t = 8.3ms, Sine) (per leg)	I <sub>FSM</sub>	150	Amps
MAXIMUM JUNCTION CAPACITANCE (V <sub>r</sub> =5V) (per leg)	C <sub>T</sub>	1000	pF
MAXIMUM THERMAL RESISTANCE (Junction to Mounting Surface, Cathode) (per leg)	$R_{ extsf{ heta}JC}$	0.77	°C/W
MAXIMUM OPERATING TEMPERATURE RANGE	Тор	-65 to + 200	°C
MAXIMUM STORAGE TEMPERATURE RANGE	Tstg	-65 to + 175	°C

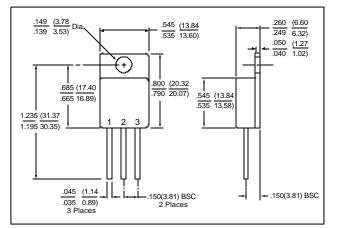
## **ELECTRICAL CHARACTERISTICS**

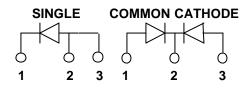
CHARACTERISTIC	SYMBOL	MAX.	UNITS
MAXIMUM FORWARD VOLTAGE DROP, Pulsed ( $I_f = 30 \text{ Amps}$ ) (per leg)			
T <sub>J</sub> = 25 °C	V <sub>f</sub>	1.01	Volts
T <sub>J</sub> = 125 °C	۷ţ	0.85	
MAXIMUM REVERSE CURRENT (Ir @ 100V PIV) (per leg)			
T <sub>J</sub> = 25 °C	l <sub>r</sub>	0.2	mA
T <sub>J</sub> = 125 °C		2.0	

## SENSITRON

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### **MECHANICAL DIMENSIONS: In Inches / mm**

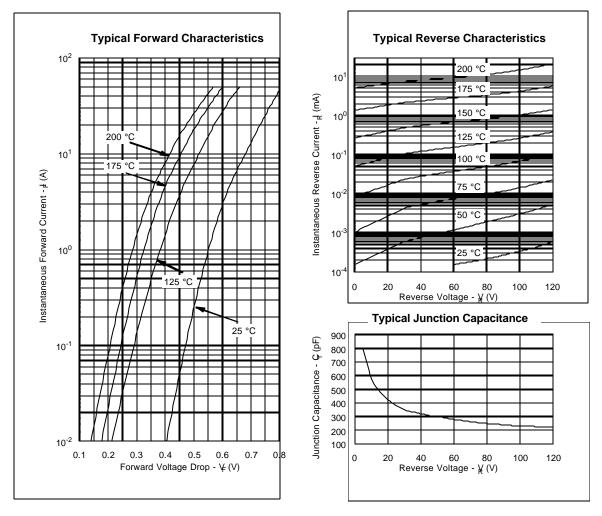




<u>TO-254</u>

## PINOUT TABLE

ТҮРЕ	PIN 1	PIN 2	PIN 3
SINGLE RECTIFIER	CATHODE	ANODE	ANODE
DUAL RECTIFIER, COMMON CATHODE (P)	ANODE 1	COMMON CATHODE	ANODE 2



Note: The  $V_f$  curves shown are for the SD175SCU100A unpackaged die only.



## **TECHNICAL DATA**

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